Absorption in atom ic wires

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The transfer matrix form alism is implemented in the form of the multiple collision technique to account for dissipative transmission processes by using complex potentials in several models of atom ic chains. The absorption term is rigorously treated to recover unitarity for the non-herm itian ham iltonians. In contrast to other models of parametrized scatterers we assem ble explicit potentials proles in the form of delta arrays, Poschl-Teller holes and complex Scarf potentials. The techniques developed provide analytical expressions for the scattering and absorption probabilities of arbitrarily long wires. The approach presented is suitable for modelling molecular aggregate potentials and also supports new models of continuous disordered systems. The results obtained also suggest the possibility of using these complex potentials within disordered wires to study the loss of coherence in the electronic localization regime due to phase-breaking inelastic processes.

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I. IN TRODUCTION

The inelastic scattering processes occurring in mesoscopic samples as a consequence of a nite non-zero tem perature can noticeably change the coherent transport ngerprints of these structures. The worsening of elec-

tronic transm ission due to such e ects is expected but in some situations the competition between the phasebreaking mechanisms and the quantum coherent interferences can improve conductance in certain energetic regimes. This is the case, for example, of disordered structures. This fact has attracted much attention in the study and modelling of dissipative transport in onedimensional structures. Interest is also prompted by experiments currently being carried out on real atom ic chains [1].

A model of param etrized scatterers coupled through additional side channels to electron reservoirs incorporating inelastic events was initially proposed by Buttiker [2], and much work has been done along this line [3]. On the other hand, inelastic processes can be modelled by sm all absorptions which in turn can be described by extending the nature of the quantum potentials to the com plex dom ain. The main purpose of this work is to include absorptive processes by perform ing these com plex extensions on previous quantum wire models developed by the authors [4] and also on other atom ic potentials.

The use of complex site energies and frequencies has already been considered in the study of electronic conductivity through one-dim ensional chains [5, 6], but nonherm itian ham iltonians have also been used to account for a large variety of phenom ena, ranging from wave transport in absorbing media [7], violation of the single parameter scaling in one-dim ensional absorbing system s [8], appearance of exceptional points in scattering theory [9] and quantum chaology [10], description of vortex delocalization in superconductors with a transverse M eissnere ect [11] and m ore phenom enologically with nuclear optical potentials. Special m ention is required for the fram ework of PT -sym m etry [12], where it is possible to consider periodic wires under com plex potentials show ing real band spectra [13, 14]. There is nothing w rong in principle with the use of non-herm itian ham iltonians as long as their properties are controlled by a su cient know ledge of the full spectrum. Indeed, renorm alization group calculations have been carried out giving rise to im aginary couplings as a result of quantum dressing of the classical real potentials [15].

An interesting modern review on absorption in quantum mechanics has appeared recently [16] and we address the interested reader to this publication and references therein.

The paper is organized as follows. In Section II we brie y review the multiple collision technique based on the transfer m atrix m ethod, and in Section III we show how unitarity can be easily restored in the presence of absorption and how the general unitarity condition can be generalized accordingly. We then turn our attention to arrays of delta potentials and calculate and draw the scattering and absorption probabilities in Section IV. In Section V, the Poschl-Teller potential is used to build atom ic chains, and its complex extension the complex Scarf potential is fully developed in Section VI. The analytical scattering probabilities are shown for a variety of composite potential proles and the elect of the im aginary parts on the transmission is analyzed. The calculations concerning exact wave functions and analytical conditions are o ered in two appendices. The paper ends with several concluding rem arks.

II. THE MULTIPLE COLLISION TECHNIQUE

The time-independent scattering process in one dimension can be described using the well known continuous

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transfer m atrix m ethod [17],

$$\begin{array}{rcl} A_{\rm R} & = & M_{11} & M_{12} & A_{\rm L} \\ B_{\rm R} & & M_{21} & M_{22} & B_{\rm L} \end{array}$$
 (1)

where A_L ; B_L (A_R ; B_R) mean the amplitudes of the asymptotic travelling plane waves e^{ikx} ; e^{-ikx} at the left (right) side of the potential. W hatever the nature of the potential is, real or com plex, the transmission matrix always veries det M = 1 as a consequence of the constant W ronskian of the solutions of the Schrödinger equation. The transmission and rejection amplitudes then read,

$$t = \frac{1}{M_{22}}; r^{L} = \frac{M_{21}}{M_{22}}; r^{R} = \frac{M_{12}}{M_{22}}$$
 (2)

where the superscripts L;R stand for left and right incidence. The insensitivity of the transm ission am plitude to the incidence direction is a universal property that holds for all kind of potentials. However, the re ectivity, although symmetric for real potentials, changes with the incidence side for a complex one unless it is symmetric [18]. The e ect of a composition of n di errent potentials can then be considered as the product of their transm ission matrices,

$$M = M_n ::: M_2 M_1 :$$
 (3)

The transm ission matrix formalism is an important tool for the numerical treatment of di erent problem s. An intuitive and general interpretation of the composition procedure can be given in the following form. Consider two potentials $V_1(x)$; $V_2(x)$ characterized by the scattering amplitudes t_1 ; r_1^R ; t_2 ; r_2^R and joined at a certain point. Then, the scattering amplitudes of the composite potential can be obtained by considering the coherence sum of all the multiple rejustion processes that might occur at the connection region,

$$t \quad t \quad t \quad t_{n=0} \quad (r_{2}^{L} r_{1}^{R})^{n} \quad t_{2} = \frac{t_{1} t_{2}}{1 \quad t_{2}^{L} r_{1}^{R}}$$
(4a)

$$\mathbf{r}^{\mathrm{L}} \quad \mathbf{r}_{1}^{\mathrm{L}} + \mathbf{t}_{1} \mathbf{r}_{2}^{\mathrm{L}} \quad (\mathbf{r}_{2}^{\mathrm{L}} \mathbf{r}_{1}^{\mathrm{R}})^{\mathrm{n}} \quad \mathbf{t}_{1} = \mathbf{r}_{1}^{\mathrm{L}} + \frac{\mathbf{r}_{2}^{\mathrm{L}} \mathbf{t}_{1}^{2}}{1 \quad \mathbf{t}_{2}^{\mathrm{L}} \mathbf{r}_{1}^{\mathrm{R}}}$$

$$(4b)$$

$$\mathbf{r}^{\mathrm{R}} = \mathbf{r}_{2}^{\mathrm{R}} + \mathbf{t}_{2}\mathbf{r}_{1}^{\mathrm{R}} = \mathbf{r}_{1}^{\mathrm{L}} \mathbf{r}_{1}^{\mathrm{L}} \mathbf{r}_{1}^{\mathrm{R}} \mathbf{r}_{1}^{\mathrm{n}} \mathbf{r}_{2}^{\mathrm{L}} = \mathbf{r}_{2}^{\mathrm{R}} + \frac{\mathbf{r}_{1}^{\mathrm{R}} \mathbf{t}_{2}^{2}}{1 + \frac{\mathbf{r}_{1}^{\mathrm{R}} \mathbf{t}_{2}^{2}}{1 + \frac{\mathbf{r}_{1}^{\mathrm{R}} \mathbf{t}_{2}^{2}} \mathbf{r}_{1}^{\mathrm{R}}} \mathbf{r}_{1}^{\mathrm{R}} \mathbf{r}_$$

Replacing the scattering am plitudes with the elements of the corresponding transm ission matrices M₁; M₂, one can trivially check that in fact these last form ulae are the equations of the product M₂M₁. Thus, the composition rules given by (4) are not restricted to the convergence interval of the series $\prod_{n=0}^{1} (r_2^{\rm L} r_1^{\rm R})^n$. They provide an explicit relation of the global scattering am plitudes in terms of the individual form er ones and can be easily used recurrently for num erical purposes. This com position technique was rst derived for a potential barrier [19] and has been used for designing absorbing potentials [20].

III. THE SCHROD INGER EQUATION FOR A COMPLEX POTENTIAL

Let us consider a one-dimensional complex potential of nite support V (x) = $V_r(x) + iV_i(x)$ (V (1) = 0). For the stationary scattering states, the density of the current ux is proportional to the imaginary part of the potential

$$\frac{dJ}{dx} = \frac{2}{\sim} V_{i}(x) j(x) j^{2}$$
(5)

where J(x) is de ned as,

$$J(x) = \frac{\sim}{2m i}$$
 (x) $\frac{d(x)}{dx}$ (x) $\frac{d(x)}{dx}$: (6)

Therefore, in the presence of a non-vanishing $V_i\left(x\right)$ the unitarity relation regarding the transm ission and re ection probabilities T (E) + R (E) = 1 is no longer valid. One can still recover a pseudounitarity relation by de ning a quantity that accounts for the loss of ux in the scattering process. Dealing with the asymptotic state ${}^{\rm L}_k$ (1) = e^{ikx} + $r^{\rm L}$ (k)e ikx , ${}^{\rm L}_k$ (+1) = t(k)e^{ikx}, one can write the asymptotic values of the ux as,

$$J_{1} = \frac{-k}{m} 1 R^{L}(k)$$
 (7)

$$J_1 = \frac{\sim k}{m} T(k)$$
(8)

yielding the relation,

$$T(k) + R^{L}(k) + \frac{m}{\sim k} (J_{1} - J_{1}) = 1:$$
 (9)

This latter equation remains the same for the right incidence case (with $\mathbb{R}^{\mathbb{R}}$ (k)) when the asymptotic state takes the form ${}_{k}^{\mathbb{R}}$ (1) = t(k)e^{ikx}, ${}_{k}^{\mathbb{R}}$ (+1) = e^{ikx} + r^R (k)e^{ikx}.

Using eq. (5) the ux term reads,

$$A^{L;R}(k) = \frac{2m}{2k} \int_{1}^{2} V_{i}(x) j_{k}^{L;R}(x) dx$$

= 1 $R^{L;R}(k) T(k);$ (10)

and it is usually understood as the probability of absorption [18]. But A (k) must be a positive de ned quantity in order to be strictly considered as a probability and this is not ensured by the de nition (unless $V_i(x) < 0.8x$). The sign of A (k) depends on both the changes in sign of the in aginary part of the potential and the spatial distribution of the state. A lthough a negative value for A (k) could be viewed as emission (because it means a gain in the ux current) it also leads the transm it ivity and the reectivity to attain anom abus values T (k) > 1; R(k) > 1, which are di cult to interpret. Let us also note that the integral representation of the absorption term is useless for practical purposes because to build the correct expression of the state $\lim_{k \to \infty} R^{L;R}(x)$ one needs to impose the given asymptotic forms to the general solution of the Schrödinger equation, therefore obtaining the scattering am plitudes, so one cannot calculate the absorption probability without knowing R (k) and T (k).

IV. SCATTER ING OF A CHAIN OF DELTA POTENTIALS

Let us consider a potential constituted by a nite array of D irac delta distributions, each one with its own coupling $_{i}$ and equally spaced at a distance a. This is probably the simplest one-dimensional model imaginable, but in spite of its apparently simplicity it supports an unexpected physical richness. It has been successfully used to model band structure in a periodic quantum wire [4] and has proved its usefulness when considering uncorrelated and correlated disorder structures [4, 21], showing interesting e ects such as the fractality of the density of states and the di erent localization regimes for the electronic states.

The global potential will be characterized by the arranged sequence of the parameters (a=a_i), where a_i = $\frac{2}{m} \frac{2}{m}$ m eans the \e ective range" of the ith delta, in the order they appear from left to right. The transmission

m atrix for a delta potential preceded by a zero potential zone of length a reads,

$$M_{j}(k) = \begin{pmatrix} 0 & 1 \\ 1 & \frac{i}{ka_{j}} e^{ika} & \frac{i}{ka_{j}} e^{ika} \\ \frac{i}{ka_{j}} e^{ika} & 1 + \frac{i}{ka_{j}} e^{ika} \end{pmatrix}$$
(11)

Considering a chain of N di erent deltas and applying the composition rules to this type of matrices one nds that it is possible to write a closed expression for the scattering am plitudes. They are given by,

$$t(k;a_1;:::;a_N) = \frac{e^{iN ka}}{f(k;a_1;:::;a_N)}$$
(12a)

$$r^{L}(k;a_{1};...;a_{N}) = \frac{g(k;a_{1};...;a_{N})}{f(k;a_{1};...;a_{N})}$$
(12b)

with the de nitions

$$f(k;a_{1};:::;a_{N}) = 1 + \frac{i}{ka} \frac{X^{N}}{j=1} \frac{a}{a_{j}} + \frac{X^{N}}{j=2} \frac{i}{ka} \frac{i}{x} \frac{Y^{N}}{a_{1}} \frac{a}{a_{2}} ::: \frac{a}{a_{1}} \frac{Y^{1}}{s} = 1 e^{2ika(r+1-r)}$$

$$g(k;a_{1};:::;a_{N}) = \frac{i}{ka} \frac{X^{N}}{j=1} e^{2ikaj} \frac{a}{a_{j}} + \frac{X^{N}}{j=2} \frac{i}{ka} \frac{i}{x} e^{2ika_{1}} \frac{a}{a_{1}} ::: \frac{a}{a_{j}} ::: \frac{a}{s} \frac{Y^{1}}{s} = 1 e^{2ika(r+1-r)}$$

$$(13a)$$

$$(13b)$$

where for each j the ^P means we are summing over the $_{j}^{N}$ combinations of size j from the set f1;2;:::;N g = f₁; 2;:::; jg with 1 < 2 < :::< j. The r^R amplitude up to a phase is obtained from r^L for the reverse chain. These latter form ulae resemble the equations for the band structure and eigenenergies of the closed system [4]. In spite of their form idable aspect, Eqs.(13) are easy to program for sequential calculations, providing the transmitivity and re ectivity of the system with exact analytical expressions.

Let us now incorporate the dissipative processes that are always present in real wires, causing energy losses. We have modelled that e ect by including an imaginary part in the potential. In this case the natural complex extension of our system consists in promoting the delta couplings from real to complex, thus writing $(a=a_j) = r_j$ is We also take $s_j > 0$ for all j in order to avoid anom alous scattering. The e ect of including complex couplings on the spectrum of an in nite periodic delta chain has recently been studied in detail [13]. Let us see what happens in a chain with open boundaries. In Fig.2 the usual scattering diagram is shown for a short periodic chain with real potentials. Including a small in aginary part in the couplings we see how the transm ission pattern is altered with a non-negligible absorption that peaks at the incoming band edges while the rejectivity is not noticeably changed. This tendency of the absorption term also appears when several species are included in the periodic array, and its pattern does not change much if only some of the couplings are complexied.

W hen the array presents no ordering at all, the graph is quite unpredictable and di erent con gurations can be obtained. In Fig.1 (a) a peaky spectrum with very sharp absorption resonances is shown. The scattering process in this case is strongly dependent on the direction incidence, as can be seen. On the other hand, sm oother diagram s are also possible in which the e ect of the com plex potential manifests through an alm ost constant absorption background and a sm all change depending upon the colliding side, like the one in Fig.1 (b).

This naive potential, apart from being exactly solvable, is powerful enough to account for very dierent physical schemes, which makes it a very useful bench-proof structure.

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FIG. 1: (Color online) Scattering process for disordered arrays of 15 deltas with complex couplings. The sequences of the real parts of the characteristic parameters are: (a) $\text{Re}(a=a_j)$: 3;1;2;0:5;3;2;1;3;0:5;4;5;1;2;2;3 (b) $\text{Re}(a=a_j)$: 1; 4; 3; 1; 2; 3; 4; 1; 2; 3; 1; 4; 4; 2; 3. The imaginary part of each coupling has been chosen as $\text{Im}(a=a_j) = 0.01$ $\text{Re}(a=a_j)$. The arrows in the legends m ark the direction of incidence.



FIG.2: (Coloronline) Scattering and absorption probabilities for one-species delta chains with length N = 15 and param – eters $(a=a_1) = 1.0$ (dashed lines) and $(a=a_1) = 1.0$ 0.015i (solid lines).

V. ATOM IC QUANTUM W ELLS

Let us go one step further and consider a potential that resembles the pro le of an atom ic quantum well with analytical solutions, the well-known Poschl-Teller potential hole. It reads,

$$V(x) = \frac{2}{2m} \frac{2}{2m} \frac{(1)}{\cosh^2(x)} > 1; \quad (14)$$

and it is shown in Fig.3.

The probability of asymptotic transmission is well



FIG. 3: Poschl-Teller potential (arbitrary units).

know n [22],

$$T_{PT}(k) = \frac{1}{1+p^2}$$
; $p = \frac{\sin(n)}{\sinh(k)}$; (15)

O ne characteristic feature of the P oschl-Tellerhole is that it behaves as an absolute transparent potential for integer values of , as can be seen from Eq.(15). From the wave functions one can also obtain the asymptotic transm ission m atrix,

$$M_{PT}(k) = \frac{ie^{i} p \frac{1+p^{2}}{1+p^{2}}}{ip} ie^{i} \frac{pip}{1+p^{2}}$$
(16)

where = $2 \arg (ik=) \arg (+ ik=) (1 + ik=) g$. Let us try to build a chain with these atom ic units. In order to do so, one has to include a sensible cuto in the potentials to ensure rst that the wave function takes a proper form at the junction regions and second that the resulting potential hole can still be described by a handy transm ission matrix, so that Eqs.(4) can be



FIG.4: (C olor online) Transm ission through a double Poschl-Teller hole with parameters $_1 = _2 = 2$ (x 1 units), $_1 = _2 = 2.4$, $d_1 = d_2 = 5$ (x units). The dashed line corresponds to a single potential hole. The inset shows the composite potential pro le (arbitrary units).



FIG. 5: (Color online) Transm ission patterns for two symmetric composite potentials of ten units each. Their proles are shown in the insets (arbitrary units). Parameters for the rst ve potentials of the sequences: (solid line) = 1;1;0:5;1;1(x¹ units), = 1:66;2:19;5:01;2:33;2:16, d = 4;4;7;4;4(x units) and (dashed line) = 2;2;1;1;1(x¹ units), = 1:66;1:66;2:03;2:03;2:03, d = 2;2;4;4;4(x units).

applied easily. The cut-o will be placed at a distance d from the center of the potential (Fig.3). The wave function in the interval [d;d] is $_2(x) = A_2e(x) + B_2o(x)$ where e(x); o(x) are the even and odd solutions respectively of the Schrodinger equation. Outside that interval the wave function is assumed to be a superposition of the free particle solutions, regions 1 and 3 in Fig.3. The connection equations at the cut-o points lead to a relationship between the amplitudes of the wave function in sectors 1 and 3 in terms of the values of e(x); o(x) and their spatial derivatives at d. Therefore, the distance d must be such that the asymptotic form of the solutions of the Schrodinger equation can be used at that point in order to ensure a sensible transition to the free particle state and to obtain a transmission matrix as simple as possible. The solutions e(x); o(x) as well as their asym ptotic form s are found in R eference 22; nevertheless they are also reproduced in Appendix A.

A fiter som e algebra one nds the transmission matrix for the cut-o version of the potential hole,

$$M(k) = \frac{ie^{i(+2kd)}p}{ip} \frac{1+p^2}{1+p^2} = \frac{ip}{ie^{i(+2kd)}p} \frac{1+p^2}{1+p^2} :$$
(17)

The matrix is the same as for the asymptotic case in Eq.(16) plus an extra phase term in the diagonal elements that accounts for the distance 2d during which the particle feels the e ect of the potential. These phases are the key quantities for the composition procedure since they will be responsible for the interference processes that produce the transmission patterns. Due to the rapid decay of the Poschl-Teller potential, the distance d adm its very reasonable values. In fact, we have seen that for a sensibly wide range of the parameters 2 [0:1;3], 2 [1;5] one can take as a minimum value for the cut-o distance $d_0 / 2d_{1=2} = 3:5=$, where $d_{1=2}$ is the half-width (Fig.3). Taking d d the connection procedure works really well, as we have checked in all cases by comparing the analytical com position technique versus a high precision num erical integration of the Schrodinger equation, obtaining an excellent degree of agreem ent.

C om posing two potential holes and applying Eqs.(4) togetherwith Eq.(17) one nds for the transmission probability, using the previously de ned quantities p,

$$T_{2PT}(\mathbf{k}) = \frac{1}{p_1^2 p_2^2 + (1 + p_1^2)(1 + p_2^2) - 2p_1 p_2} \frac{1}{1 + p_1^2} \frac{p_1^2 p_2^2}{1 + p_2^2} \cos(1 + 2 + 2k(d_1 + d_2))};$$
(18)

which is a handy expression that can hardly be obtained by trying to solve the Schrödinger equation for the double potential hole. To our know ledge this calculation has not been made before. Eq.(18) clearly shows the interference e ect depending on the distance $d_1 + d_2$ between the centers of the holes. An example of transmission is



FIG. 6: Real and in aginary parts of the complex Scarf potential (arbitrary units).

shown in Fig.4.

The composition procedure can be applied with a sm all number of atoms to study the transmitivity of dierent potential proles resembling molecular structures such as those in Fig.5. The transmission matrix (17) can also be used to consider a continuous disordered model in the form of a large chain of these potential holes with random parameters. So far, in the literature only two kinds of potentials have been used to build continuous disordered models, namely the Dirac delta potential and the square well(barrier), due to their well known and easy to manipulate transmission matrices. We recall the fact that handy transmission matrices can be obtained for other potential pro les using reasonable approximations, such as the one described here.

The next step for our purpose is to consider dissipation in these one-dimensional composite potentials.

VI. DISSIPATIVE ATOM IC QUANTUM W ELLS/BARRIERS

W e shall consider the extension of the Poschl-Teller potential given by the com plexi ed Scarfpotential,

$$V(x) = \frac{2^{2}}{2m} \frac{V_{1}}{\cosh^{2}(x)} + iV_{2}\frac{\sinh(x)}{\cosh^{2}(x)}$$
(19)

with V_1 ; V_2 2 R. It is a proper complex extension for two reasons: it adm its analytical solutions [23] and its im aginary part is som enow proportional to the derivative of the real potential. This latter criterion has been considered in nuclear optical potentials to choose adequate complex extensions. It seems reasonable to measure the strength of the dissipation processes in terms of the \density" of the real interaction and therefore writing an imaginary potential that is proportional to the spatial derivative of the real one. The potential processes here the strength of the real one. The potential processes here the strength of the real one.

The Scarfpotential has been extensively considered in the literature, mainly dealing with its discrete spectrum, either in its real and complex forms, from the point of view of SUSY Q uantum M echanics [24] or focusing on its PT-symmetric form [25].

First, a detailed m athem atical analysis of the potential, regarding its scattering properties, m ust be m ade to discuss som e new features and som e assertions that have been m ade.

The left scattering am plitudes of the real Scarf potential have been obtained in terms of com plex G am m a functions [23]. Recently, a considerable sim pli cation has been pointed out by A hm ed [25]. In fact, the asym ptotic transm itivity and re ectivity for the com plex Scarf can be written as,

$$T(k) = \frac{\sinh^{2}(2 \ k=)}{\sinh^{2}(2 \ k=) + 2\cosh(2 \ k=)\cosh((g_{+})\cosh((g_{+}) + \cosh^{2}((g_{+}) + \cosh^{2}((g_{+})))}$$
(20)
$$R^{L}(k) = \frac{\cosh^{2}((g_{+})e^{2 \ k=} + \cosh^{2}((g_{+})e^{2 \ k=} + \cosh^{2}((g_{+}))\cosh((g_{+}))\cosh((g_{+}))}{\sinh^{2}(2 \ k=) + 2\cosh(2 \ k=)\cosh((g_{+}))\cosh((g_{+}) + \cosh^{2}((g_{+})))}$$
(21)

where $g = {}^{p} \overline{V_{1} \quad V_{2} \quad 1=4}$ and R^{R} (k) is recovered from R^{L} (k) by interchanging g_{+} and g (which is equivalent to substituting V_{2} ! V_{2} and therefore changing the direction of incidence). These expressions derive from the asymptotic transmission matrix, which is obtained here using the asymptotic form of the Schrödinger equation solutions (Appendix B),

$$M_{\text{Scarf}}(k) = \frac{ie^{i'} p \overline{1 + s\overline{s}}}{i\overline{s}} \qquad ie^{i'} p \frac{is}{1 + s\overline{s}} \qquad (22)$$

where

$$s = \frac{\cosh(g_{+})e^{k} + \cosh(g_{-})e^{k}}{\sinh(2k}$$
(23)

$$\bar{s} = s(g_+ g)$$
 (24)

and ' = 2 argf (ik=) (1=2 + ik=)g argf (c + ik=) (b + ik=) (1 c + ik=) (1 b + ik=)g with the de nitions

$$c = \frac{1}{2} - \frac{i}{2}(g_{+} - g_{-})$$
; $b = \frac{1}{2} - \frac{i}{2}(g_{+} + g_{-})$: (25)

It im mediately follows from the transmission matrix that

| V_1 | ĴV₂j | \mathbf{j}_2 jem issive |
|-------|------------------------------------|-----------------------------|
| 0:5 | [0;0:5][[1:5;5:5][[11:5;19:5]::: | [0;0 : 5] |
| 1 | [D;5][[11;19][[29;41]::: | ; |
| 2:4 | [0;0:4][[2:4;3:6][[9:6;17:6]::: | [0;0:4] [[2:4;2:569] |
| 3 | [0;1][f3g[[9;17]::: | [0 ; 1] |
| 4 | [0;4][[8;16][[26;38]::: | [3 : 606 ; 4] |
| 5 | [0;1][[3;5][[7;15]::: | [3;4:123] [[4:472;5] |

TABLE I:R anges of V_2 com patible with the condition T (k) 1 8 k for the complex Scarf potential for certain negative values of V_1 . The last column includes the intervals providing physical scattering from the emissive side of the potential.

the absorption probabilities read,

$$A^{L}(k) = \frac{s\overline{s} - s^{2}}{1 + s\overline{s}}$$
; $A^{R}(k) = \frac{s\overline{s} - s^{2}}{1 + s\overline{s}}$: (26)

Unlike the complex delta potentials example this potential has some draw backs that must be carefully solved. Its imaginary part is non-negative de ned in its domain, which might cause anom alous scattering. Only some values of V₂ will be physically acceptable. To ensure that T (k) 1 8 k, it is clear from Eq.(20) that the necessary and su cient condition is $\cosh(g_+)\cosh(g_-) = 0$. The functions g_+ , g_- can be real or pure in aginary depending on the values of V₁ and V₂. A detailed analysis of the conditions for physical transmission is presented in Appendix B. As a sum mary, let us say that for V₁ > 0 (barriers), the evaluation of the condition translates into,

$$y_2 j2 [0; V_1][$$

[2n (2n 1) + $V_1; 2n (2n + 1) + V_1$] n 2 Z⁺:
(27)

For $V_1 < 0$ (wells) the situation becomes more complicated and the result can only be expressed through several inequalities, each one adding a certain allowed range for V_2 (see Appendix B). As an example, in Table I we show the compatible ranges of V_2 for a few negative values of V_1 . One can trivially check the compatibility of the intervals presented for V_2 with the condition T (k) 1 8 k by plotting Eq.(20). In a two dimensional plot of y_2 jvs. V_1 , the physical ranges for the transmission distribute as alternating fringes and a funny chessboard like pattern (Fig.9).

O ne feature to emphasize according to the conditions given for acceptable transmission is the fact that the number of permitted intervals for V_2 is in nite for any V_1 , either positive (barrier) or negative (well), and therefore there is no m athem atical upper bound on $y_2 j(y_2^{\text{critical}})$ above which the transmission probability always becomes unphysical, contrary to what has been reported recently [25]. From a physical view point of course, a sensible lim – itation must also be in posed on V_2 , usually $jy_2 j = jy_1 j$.

Let us see now what happens with the re ectivity. We assert that for the values of V_1 and V_2 preserving a physical transm ission, one of the re ectivities of the system

| | | (V ₁ , jV ₂ j) | | |
|-----------------|----------------|---------------------------------------|------------------|------------------|
| (1;1) | (3 ; 3) | (6;6) | (10;10) | (15 ; 15) |
| [2;0] | (4;2) | (7 ; 5) | (11;9) | (16;14) |
| [6 ; 0] | (9 ; 3) | (13 ; 7) | (18;12) | (24;18) |
| [12 ; 0] | (16;4) | (21;9) | (27 ; 15) | (34 ; 22) |

TABLE II: Some correlated values of V_1 ; V_2 producing the fully resonant behaviour of the com plex Scarf potential. The particular Poschl-Teller resonances are in square brackets.

remains physical (i.e. R (k) 1 T (k) 8 k), left or right, depending on the particular values of V_1 ; V_2 (or equivalently, one of the absorptions takes positive values for all k). The statement is easy to prove from Eqs.(26) and more speci cally reads: when T (k) 1 8 k (i.e. $\cosh(g_+)\cosh(g_-)$ 0), then

$$j\cosh(g)j < j\cosh(g_+)j) A^{\perp}(k) 0 8k$$

 $j\cosh(g)j > j\cosh(g_+)j) A^{R}(k) 0 8k$:
(28)

Considering $V_1 > 0$ and $V_2 > 0$ it is not hard to see that the rst of the above inequalities always holds. Therefore, in the case of a potential barrier the scattering is always physical from the absorptive side (trough of the imaginary part), as has already been stressed [25]. More interesting is the fact that this conclusion cannot be extended to the case $V_1 < 0$ (well). In this case the physical scattering sometimes occurs from the emissive side (peak of the imaginary part), producing smaller absorption terms. In Table I a few examples of V_2 intervals providing physical scattering from the emissive side for some potential wells are shown.

A nother interesting feature that must be observed is that there exists a set of correlated values of $V_1; V_2$ for which the complex Scarfpotential behaves as fully transparent. The condition for this to happen is from Eq.(20) $\cosh(g_+) = \cosh(g_-) = 0$. Thus, the main requirement is that $g_+; g_-$ must be pure in aginary, yielding in this case the transparency equations,

$$cos \quad \frac{r}{\frac{1}{4}} \quad V_1 \quad V_2 = 0 \tag{29}$$

whose solution is,

$$V_1 = \frac{1}{4} - \frac{1}{8} (2m + 1)^2 + (2n + 1)^2$$
 (30a)

$$V_2 = \frac{1}{8} (2m + 1)^2 (2n + 1)^2 m; n 2 Z:$$
 (30b)

It is worth noting that the transparencies only appear for potential wells ($V_1 < 0$). Considering the particular case n = m one recovers the Poschl-Teller resonances (2 Z). In Table II the rst values of Eqs.(30) are listed explicitly.

The absorption obviously vanishes for all k when considering these special resonant values of the potential am plitudes. Surprisingly, there also exists another set of



FIG. 7: (Color online) Characteristic scattering patterns for (a) a complex Scarfwell = $1 (x^{1} \text{ units})_{v} V_{1} = 0.5; V_{2} = 0.4$ and (b) a complex Scarfbarrier = $1 (x^{1} \text{ units})_{v} V_{1} = 2; V_{2} = 0.1$.

non-trivial correlated values of $V_1; V_2$ for which the potential is non-dissipative (A (k) = 0 8 k) without being fully transparent. This set of values satis es $\cosh(g_+) = \cosh(g_-) \in 0$, as can be seen from Eqs.(26). Non-trivial solutions exist when $g_+; g_- 2$ C, yielding,

$$y_2 j = n \frac{p}{1 + 4V_1 + 4n^2} n 2 Z^+$$
: (31)

Let us also notice from Eqs.(28) that these solutions are also the borders where the physical scattering changes from the absorptive side to the emissive side or vice versa. W e shall refer to these borders as inversion points (\mathbb{P}) . Therefore, whenever we encounter an \mathbb{P} we can say A(k) = 0 8 k w ithout a fully transparent behaviour, and hence a non-dissipative scattering process for all energies with a non-vanishing imaginary part of the potential. Let us note that from Eq.(31) the IP only appears in the case of Scarf potential wells and only for ĴV₂j 1 = 4V. In Fig.7 the characteristic scattering probabilities are shown for a Scarf barrier and a Scarf well, and in Fig.8 the maximum value of the physical absorption is plotted versus $y_2 j$ for di erent values of V_1 . W hen V1 is positive the absorption grows with the amplitude of the imaginary part of the potential. On the other hand, for negative V_1 a strikingly di erent pattern arises, with transparencies (T) and inversion points (\mathbb{P}) and the absorption does not increase m onotonically with V_2 j. The whole behaviour of the scattering can be clearly understood by building a two dimensional diagram y_2 j vs. V1 (Fig.9), including physically perm itted ranges, inversion lines and the points of transmission resonance. The complex Scarf potential shows two opposite faces to scattering, namely barrier and well, and a much richer structure in the latter case.

A fler this detailed analysis of the peculiarities of the com plex Scarf, that to our know ledge have not been reported before, let us continue with our work on connecting several potentials to model dissipative atom ic chains. The procedure is the same as the one described for the Poschl-Teller potential hole in Section V. Only the portion of the potential included in the interval [d;d] is taken (Fig.6). Making use of the asymptotic forms of the wave functions, and after som e algebra, one nds the



FIG.8: Maximum value of the absorption probability A_{max} vs. $jy_2 j$ for dimensional dimensiona dimensi dimensional dimensional dimensional dimensional dime



FIG.9: Scattering diagram for the complex Scarfpotential in terms of the potential amplitudes. The physically acceptable ranges for V_1 ; V_2 correspond to the shaded zones. The curves are the inversion lines given by Eq.(31). The black points mark the correlated values of the amplitudes (Eqs.(30)) generating a fully transparent behaviour.

transm ission m atrix for the complex $\operatorname{Scarfpotential} w$ ith a symmetrical cut-o $\ ,$

$$M (k) = \frac{ie^{i('+2kd)}p \frac{1}{1+s\bar{s}}}{i\bar{s}} = \frac{is}{ie^{i('+2kd)}p \frac{1}{1+s\bar{s}}} :$$
(32)

The m atrix proves to be the sam e as for the asymptotic case (Eq.(22)), but with the extra phase 2kd in the diagonal terms. It can be checked that the half-widths $d_{1=2}$ of both the real and in aginary parts coincide and that the decay of the in aginary part of the potential is always shower than that of the real part (Fig.6). This causes an increase in the minimum value of the cut-o distance d_0 with regard to the Poschl-Teller case. For sensible values of the potential amplitudes we have found



FIG.10: (C obr online) Scattering probabilities for double Scarf potentials with parameters $= 1 (x^{-1} \text{ units}), V_1 = 2; V_2 = 1$ for barriers and $= 1 (x^{-1} \text{ units}), V_1 = 4; V_2 = 3:1$ for wells. The solid lines were obtained from the analytical composition technique and the dashed lines correspond to the exact numerical integration of the Schrödinger equation. The insets show the potential probe (in arbitrary units) for each case: solid line for the real part and dashed for the in aginary part. The vertical lines limit the portion of the potential that the composition technique takes into account. For numerical integration the whole potential probe was considered. Notice that for low d the exact integration may lead to unphysical scattering because the conditions obtained for physical scattering are not valid for such d values. As d is increased an acceptable scattering is recovered and both m ethods start converging. Convergence is reached faster in the case of potential barriers where the analytical composition technique works in pressively well even for very low values of d.

that considering d_0 ' $3d_{1=2} = 5:3=$ is enough in most cases. In fact, this minimum value can be relaxed in the case of potential barriers $(V_1 > 0)$, whereas for potential wells taking d below this value to apply the connection equations m ay som etim es distort the results. The correct behaviour of the connection procedure for d d can be observed in Fig.10 where the scattering probabilities obtained upon integrating the Schrodinger equation num erically are compared with those given by the analytical composition technique, for two potential barriers and two potential wells with di erent choices of the cuto distance and with high values for $\mathbf{j}V_2 \mathbf{j}$. Notice how in the barrier example convergence between the m ethods is completely reached for d ' $2d_{1=2}$ whereas for potential wells a further step is needed because the convergence is much slower.

Once the connection of potentials has been successfully made, one should ask which are the ranges of the potential amplitudes that provide an acceptable physical scattering in this new fram ew ork. A nalysis of this issue is very non-trivial and quite com plex analytically, but also very im portant because it determ ines whether this model

rem ains useful when considering atom ic chains. First, in the case of two potentials we have observed that choosing each individual pair of am plitudes $(V_1; V_2)$ belonging to a physical range, and selecting the signs of the im aginary parts so that the physical faces of both potentials point in the same direction, then an acceptable scattering for the composite potential can always be recovered at least from one of the two possible orientations (both physical faces to the right or to the left). In other words, considering that the incident particle always collides with the left side (it com es from 1) and therefore orientating the individual physical faces to the left, then at least one of the sequences V_{I} (x) V_{II} (x) or V_{II} (x) V- (x) gives an acceptable scattering for all energies. We have checked this assertion for a broad variety of Scarf couples. For a higher num ber of potentials the situation becomes more complex but a few pseudo-rules to obtain physical scattering can be deduced. For an arbitrary chain we have found that in m any cases the left scattering remains physical as long as: the left scattering of each individual potential is physical and the left scattering of each couple of contiguous potentials is physical. This

recipe seem s com pletely true when com posing potential barriers only, whereas when wells are included it fails in som e situations, especially when several contiguous wells are surrounded by barriers. A lithough at the beginning it m ay appear alm ost random to recover a physical scattering from a large com position of Scarfs, following the given advices it turns out to be m ore system atic.

Let us remember that the composition procedure,

apart from being a powerful tool for num erical calculations also provides analytical expressions for the scattering probabilities, which of course adopt cum bersom e form s for a large num ber of potentials but are useful for obtaining sim ple expansions for certain energetic regim es. Just as an exam ple, the transm itivity and left re ectivity for the double Scarf read,

| т. (к) – | | | |
|-----------------------------------|---|---|------|
| $1_{2S \text{ carf}}(K) -$ | $s_1^2\overline{s}_2^2$ + (1 + $s_1\overline{s}_1$) (1 + $s_2\overline{s}_2$) | $2q\overline{s}_2 \overline{s}_2 \overline{1+s_1} \overline{s}_1 \overline{1+s_2} \overline{s}_2 \cos(t_1 + t_2 + 2k(d_1 + d_2))$ | (55) |
| \mathbf{P}^{L} $(k) =$ | $\overline{s}_1^2 (1 + s_2 \overline{s}_2) + \overline{s}_2^2 (1 + s_1 \overline{s}_1)$ | $Z_{\bar{3}} \bar{s}_{2}^{p} \frac{p}{1 + s_{1} \bar{s}_{1}^{p}} \frac{p}{1 + s_{2} \bar{s}_{2}} \cos(\prime_{1} + \prime_{2} + 2k(d_{1} + d_{2}))$ | (34) |
| $K_{2S carf}(K) -$ | $s_1^2 \overline{s}_2^2 + (1 + s_1 \overline{s}_1) (1 + s_2 \overline{s}_2)$ | $2q \overline{s}_2 \frac{7}{1+s_1 \overline{s}_1} \frac{7}{1+s_2 \overline{s}_2} \cos(t_1 + t_2 + 2k (d_1 + d_2))$ | (54) |

m aking use of the previously de ned term s s; \overline{s} and '. O ne in portant feature of the form ulae for the com posite scattering probabilities is the fact that they analytically account for the fully transparent behaviour of the whole structure as long as there is resonant forward scattering of the individual potential units, as can be seen from the latter equations and also from Eq.(18) for the double Poschl-Teller. A nother curious feature arises when com posing di erent potentials whose am plitudes describe an IP. In this case the whole structure remains non-dissipative (Fig.11). M oreover, the com plex Scarfs at these points behave com pletely as real potentials, providing an acceptable scattering for the com position that is independent of the incidence direction for any sequence of the individual Scarfs.

Considering larger Scarf chains with sm all im aginary parts of the potentials, in the case of a periodic array we observe that the absorption term remains at over a wide range of forbidden bands and oscillates inside the permitted ones. The variations in the absorption are entirely balanced by the re ectivity while the transm itivity is surprisingly not a ected by the presence of a small complex potential (Fig.12). This behaviour contrasts strongly with the complex delta potentials periodic chain where the absorption was completely di erent and it was the re ectivity that was little a ected by the dissipation. For an aperiodic sequence the situation is quite di erent, as expected. In Fig.13 a type ofm olecular aggregate is modelled with complex Scarfs. It exhibits a peaky absorption spectrum and a strongly oscillating transmitivity with sharp resonances. In Fig.14 a symmetric atom ic cluster has been considered in which the dissipation only occurs at both ends. D i erent transm ission and absorption con gurations can be obtained by building di erent structures. This shows the usefulness and versatility of this model for being able to account for a variety of possible experim ental observations.

A sa nalexercise, two examples are included in Fig.15 showing the evolution of the transmitivity of two di erent

FIG.11: (Color online) Composition of Scarfs with di erent pair amplitudes describing IPs. Sequence with $p = 1 (x_1^p units)$ and $y_1; y_2$: (4; 13), (4:5; 15), (5; 17), (6; 21), (7; 213). All the cut-o distances have been taken equal to d = 6 (x units). The inset shows the potential prole with solid (dashed) line for the real(in aginary) part in arbitrary units. Notice that the composition remains non-dissipative.

Scarf com positions as a function of the imaginary part of the potential. The transm ission patterns are plotted for di erent values of the parameter " = $j_{2} \neq j_{1} j$ which m easures the strength of the imaginary part. The transmission e ciency is evaluated using an averaged transmission e ciency R_{k_2} T (k) dk= (k_2 k) corresponding to the area enclosed by T (k) per energy unit in a characteristic energy range, namely the zone where T evolves until it becomes saturated. The imaginary potential tends to sm ooth the transmission pattern in the rst example (corresponding to a sequence of barriers), causing a slight decrease in the averaged transmitivity for low ", although



FIG.12: (Color online) Periodic chain of 20 complex Scarfs with amplitudes = $1 (x^{1} \text{ units}), V_1 = 2, V_2 = 0.02$ (solid lines) and $V_2 = 0.05$ (dashed lines) and cut-o distance d = 6 (x units). The transmitivity is not changed much by the sm all imaginary part of the potentials.



FIG. 13: (Color online) Scattering probabilities for a 10-Scarf structure with parameters = $1(x^{1} units)$ and $(V_{1};V_{2})$: (1;0), (05; 0:005), (13;0:013), (18;0:01), (13;0:013), (4;0:04), (2:4; 0:024), (35;0:04), (3:1;0:031), (15;0:04). The cut-o distance is d = 6(x units) equal for all of them. The inset shows the real part of the potential probe (arbitrary units).

it is nally in proved. For a double well a di erent e ect occurs. T_{int} is always enhanced with increasing " until it reaches a maximum, after which the transmitivity falls with the imaginary potential. With these results in m ind one could speculate that these models might also be useful to describe the phase-breaking inelastic scattering processes in atom ic chains. Especially when one treats disordered arrays where the break of the localization regime could arise as a result of the loss of coherence due to inelastic collisions.



FIG. 14: (Color online) Scattering probabilities for a 10-Scarf structure with parameters = $1(x^{1} \text{ units})$ and $(V_{1};V_{2})$: (1;0:04), (1;0:05), (2;0), (1:5;0), (1;0), (1:0), (1:5;0), (2;0), (1:0:1), (1:0:1). The cut-o distance is d = 6(x units) equal for all of them. The inset shows the real part of the potential prole (arbitrary units).

VII. CONCLUDING REMARKS

In this work we have used the transfer matrix formalism in the form of the multiple collision technique to model dissipative scattering processes by using com – plex potentials in various models of atom ic chains. The absorption probability has been rigorously included to recover unitarity for the non-herm itian ham iltonians.

New exact analytical expressions are given for the scattering am plitudes of an arbitrary chain of delta potentials. The absorption e ects arising by promoting the delta couplings to the com plex dom ain have been shown, revealing the exibility of this sim ple model to account for very di erent physical schemes.

H andy expressions for the transm ission m atrices of the Poschl-Teller and the complex Scarf potential have been constructed in their asymptotic as well as their cut-o versions for the st time. These latter matrices have m ade feasible, via the composition technique, the assem bly of an arbitrary number of potentials to build atom ic one-dimensional wires that can incorporate absorptive processes. Dierent absorption con gurations are presented in several examples that show the versatility of the model to account for a variety of possible experim ental observations. The procedure developed is not only useful for num erical calculations but also provides analytical form ulae for the composite scattering probabilities, which have not been obtained by other methods, and whose signi cance has been checked by num erical integrations of the Schrodinger equation.

From a more mathematical view, a complete and rigorous analysis of the scattering properties of the com plex Scarf potential has been carried out. The ranges of physical transmission have been obtained and a group of



FIG.15: (Color online) Transm itivity for di erent strengths of the imaginary part of the potentials in (a) a chain of 6-Scarf barriers $V_1 = 4;2;2:5;3;3:5;4$ and $= 1 (x^{1} \text{ units})$, (b) a double Scarf well with $V_1 = 1$; 1 and $= 2 (x^{1} \text{ units})$. The cut-o distances in all cases are equal to d = 6 (x units). Each imaginary amplitude reads $V_2 = "j_1 j$ except the rst barrier in example (a) which is maintained real. The insets show the evolution of T_{int} vs the strength of the imaginary amplitudes.

novel features have arisen such as the presence of perfect transparencies and inversion points.

A part from being able to include dissipation in the system s in a tractable way, the tools and m ethods provided m ay have direct applicability for considering m olecular aggregates [26] and other structures with explicit potential pro les and also to build a new kind of continuous disordered m odels.

Future work seems promising since we are already in progress on the assembly of the one-dimensional structures to quantum dots in order to analyze the e ect of dissipation on the conductance. Our aim is also to treat long disordered wires within this fram ework, and in particular to study the applicability of these potentials to account for the loss of coherence due to inelastic scattering process in the electronic localization regime.

A cknow ledgm ents

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APPENDIX A: SOLUTIONS OF THE POSCHL-TELLER POTENTIAL

The elementary positive energy solutions of the Schrodinger equation with potential (14) read,

$$e(x) = \cosh(x)F = a;b;\frac{1}{2}; \sinh^2(x)$$
 (A1a)

$$o(x) = \sinh(x)\cosh(x)$$

F $a + \frac{1}{2};b + \frac{1}{2};\frac{3}{2}; \sinh^{2}(x)$ (A1b)

where $a = \frac{1}{2} + i\frac{k}{2}$, $b = \frac{1}{2}$ $\frac{ik}{2}$ and F (a;b;c;z) is the H ypergeom etric function. And their asymptotic forms can be written as,

$$e(x) ! m e^{i'} e^{ikjxj} + m e^{i'} e^{ikjxj}$$
 (A 2a)

$$o(x)$$
! sign(x) ne ⁱ e ^{ik jx j} + neⁱ e^{ik jx j} (A 2b)

where

$$m e^{i'} = \frac{p - i^{\underline{k}} 2^{i^{\underline{k}}}}{\frac{1}{2} + i^{\underline{k}}_{2}} \frac{1}{\frac{1}{2} + i^{\underline{k}}_{2}}$$
(A 3a)

$$ne^{i} = \frac{P - i^{k} 2^{i^{k}}}{2 - \frac{+1}{2} + i^{k} 2} - 1 - \frac{i^{k}}{2} + i^{k} 2^{i^{k}}} : \quad (A 3b)$$

APPENDIX B:COMPLEX SCARF POTENTIAL

1. Scattering states

The elementary positive energy solutions of the Schrodinger equation with the complex Scarf potential

13

(19) are,

$$u_{1}(x) = e^{-i(b-\frac{1}{2})\arctan(\sinh(x))}\cosh^{c}(x)$$

$$F = c + i\frac{k}{1}; c = \frac{k}{1}; 1 = b + c; \frac{1}{2} + \frac{i}{2}\sinh(x)$$
(B1a)
$$u_{2}(x) = e^{-i(b-\frac{1}{2})\arctan(\sinh(x))}\cosh^{c}(x)$$

$$\frac{1}{2} + \frac{i}{2}\sinh(x)$$

$$F = b + i\frac{k}{1}; b = \frac{k}{1}; 1 + b = c; \frac{1}{2} + \frac{i}{2}\sinh(x)$$

F (a;b;c;z) being the hypergeom etric function and using the b;cde nitions in (25). The asymptotic lim it x! 1 yields,

where

$$w_{1} = \frac{2^{2i^{\underline{k}}} (1 \quad b+c) \quad 2\frac{k}{E} e^{\operatorname{sign}(x)\frac{z^{\underline{k}}}{2}}{c \quad \frac{k}{E} \quad 1 \quad b \quad \frac{k}{E}}$$
(B 3a)

$$w_{2} = \frac{2^{2i^{\underline{k}}} (1 \quad b+c) \quad 2i^{\underline{k}} e^{\operatorname{sign}(x)\frac{z^{\underline{k}}}{2}}{c+i^{\underline{k}} \quad 1 \quad b+\frac{k}{E}}$$
(B 3b)

$$q_{1} = w_{1} (b \quad c)$$
(B 3c)

$$q_{2} = w_{2} (b \quad c) :$$
(B 3d)

2. Physical transm ission

The condition for physical transmission is $\cosh(g_{+})\cosh(g_{-}) = 0$. V_{2} can be considered positive with no loss of generality since its change in sign (which is equivalent to changing the side of incidence) does not a ect the transmission. With the de nitions $X = jV_{1}j = V_{2}$ and $Y = jV_{1}j + V_{2}$, the study can be easily carried out. Considering $V_{1} > 0$ the inequality translates into the permitted regions

(

$$X > 0$$

 $X > 0$
 $2n(2n + 1)$ $X = 2n(2n - 1) n 2^{+}Z$
(B 4)

which is clearly a sequence of allowed vertical fringes in the negative X quadrant and the whole positive X quadrant. This pattern will be same but rotated =4 clockw ise when the change of variables is undone. More speci cally, in term s of the potential amplitudes the allowed intervals can be written as

$$V_2$$
 j2 [0; V_1][
[2n (2n 1) + V_1 ; 2n (2n + 1) + V_1] n 2 Z⁺:
(B 5)

In the case of $V_1 < 0$ a careful analysis leads to the following cum bersom e allowed sets

| X < 0) | 2n (2n 1) | Y | 2n(2n + 1) n = 2 | 1;2;3;::: | | | (B6) |
|--------|-----------|---|------------------|-------------|---|-------------------------------|-------|
| X > 0) | 2n (2n 1) | Х | 2n (2n + 1) | _2m (2m 1) | Y | 2m (2m + 1) n;m = 1;2;::: | /D 7) |
| | 2j(2j+ 1) | Х | 2j(2j+ 3)+ 2 | 2k (2k + 1) | Y | 2k(2k + 3) + 2 k;j= 0;1;2;::: | (0) |

(B1b)

(B2b)

which are a set of allow ed horizontal fringes in the negative X quadrant and a chessboard like structure for positive X. Undoing the change of variables will mean a =4 clockw ise rotation follow ed by a rejection around the vertical axis of this pattern to recover the negative axis of

 V_1 . Solving these inequalities in terms of the potential amplitudes gives rise to the following set of inequalities, each one assigning a certain allowed interval for \dot{y}_2 jwhen fulled,

(B8)

for n 2 Z^+ ,

$$y_1$$
j n (2n 1)) 2n (2n 1) y_1 j 2n (2n + 1) y_1 j
n (2n 1) y_1 j n (2n + 1)) y_1 j 2n (2n + 1) y_1 j

form;n2Z⁺ m n, m (2m 1) + n (2n m (2m 1) + n (2n + 1)) 2m (2m 1) ∱yj; 2n (2n 1) ij 1) + j⁄jj m (2m 1) + n(2n + 1)j∕ij m (2m + 1) + n (2n 1)) $2n(2n + 1) + \sqrt[4]{7} 2n(2n$ 1) + †⁄j (B9) $2n(2n + 1) + \frac{1}{2}i_{2}2m(2m + 1)$ m (2m + 1) + n (2n 1) j∕jj m(2m + 1) + n(2n + 1))jИј and for j;k = 0;1;2;...kj, k(2k + 1) + j(2j + 1)Ъ́л k(2k + 1) + j(2j + 3) + 1) = 2k(2k + 1) $\frac{1}{1}$, $\frac{1}{2}$, k(2k + 1) + j(2j + 3) + 1Ъ́і k(2k + 3) + 1 + j(2j + 1))2 $2j(2j+3) + \frac{1}{2}j(2j+1) + \frac{1}{2}j(2j+1)$ k(2k + 3) + 1 + j(2j + 1)Ъ́лј k(2k + 3) + j(2j + 3) + 2)2 $2j(2j+3) + \frac{1}{2}j(2k+3)$ <u></u>йј: (B10)

In the particular cases m = n for Eqs.(B9) and k = j for Eqs.(B10) only the positive part of the allowed intervals

m ust be considered. The total physical range for $y_2 j$ com es from the union of the di erent perm itted intervals.

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